

RX210

Motor Control with Space Vector Modulation

R01AN1193ET0101 Rev.1.01 Jan 23, 2013

Introduction

The objective of this project is to implement RX210 MCU base application board and software control reference for Permanent Magnetic Synchronous Motor (PMSM) control with Power Factor Corrector (PFC).

Target Device

RX210

Contents

| 1. | Specifications | 2 |
|----|----------------------------------|------|
| 2. | PFC Controller Design | 4 |
| 3. | Controller Design of PMSM Drives | 6 |
| 4. | Start Up Procedure | . 11 |
| 5. | Software Implementation | . 13 |
| 6. | Experimental Results | . 14 |
| 7. | Conclusion | . 18 |
| 8. | Reference | . 19 |



1. Specifications

- Target Device: RX210
 - PFC
 - Input voltage: 110 V AC/60 Hz
 - Output voltage: 200V DC
 - Output power: 400W
 - Power factor: >0.9
 - Current Control Mode: Average current mode
 - Controller Type: PI Controller
 - Carrier Frequency: 20 kHz
 - Module: One phase Time

PFC

- Power: 300 W
- Rated speed: 3000 rpm
- Type: Surface mount PMSM
- Module: Three phase Timer
- Controller: Speed and current control
- Controller Type: PI Controller
- Carrier Frequency: 20 kHz

Figure 1 and Figure 2 shows the block diagram for the implementation of PFC and PMSM drives. As shown in Figure 1, RX210 is used to realize the control software of PFC and PMSM drives. In Figure 1, average current mode and speed/current control are realized in software using RX210. Table 1 and Table 2 show the specifications of PFC and PMSM used in this project.

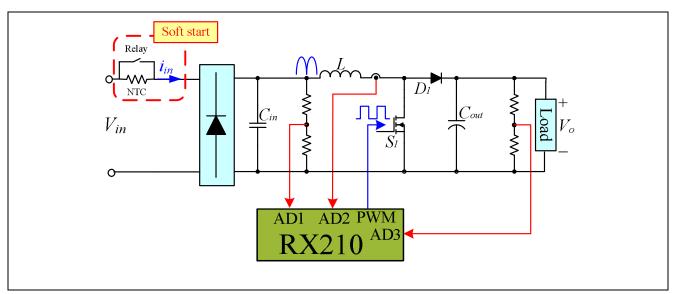


Figure 1 Power Factor Corrector



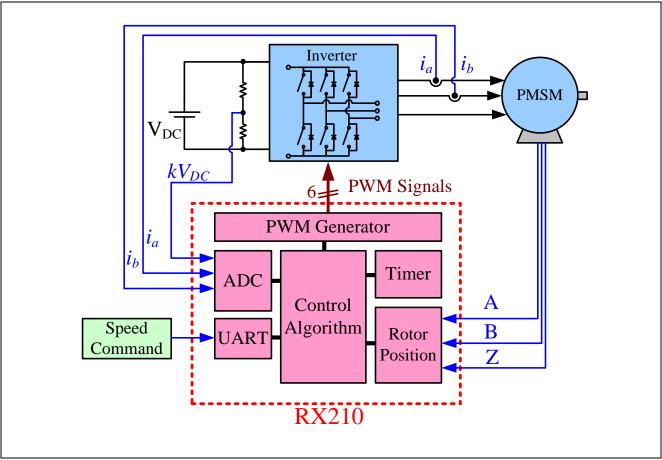


Figure 2 Vector-controlled PMSM drive

Table 1 Specifications of PFC

| Parameters | Value |
|----------------------------------|------------------------------|
| Input voltage, V _{in} | • 110VAC/60Hz |
| Output voltage, V _{out} | • 220VDC |
| Power rate, P _o | • 400W |
| Current control mode | Average current mode control |
| Power factor | • 0.90-0.98 |
| Switching frequency | • 20KHz |

Table 2 Specifications of PMSM

| Parameters | Value | |
|--------------------------------|---------------------------|--|
| Rated Power | • 300W | |
| Rated Current (rms) | • 2A | |
| Rated Speed | • 3000 RPM | |
| Rated Torque | • 0.95 Nt-m | |
| Poles No. | • 8 | |
| Encoder Resolution | • 2000 C/T | |
| q-axis Stator Inductance (Lqs) | • 5.63 mH | |
| d-axis Stator Inductance (Lds) | • 6.47 mH | |
| Flux Linkage (λ_m) | • 0.06 V-s/rad | |
| Stator Resistance (Rs) | 2.65Ω | |



2. PFC Controller Design

Table 3 shows the circuit parameters of the designed PFC. The block diagram of the implementation is shown in Figure 3. As shown in Figure 3, the output voltage is sensed to give the magnitude of current reference via the voltage controller. Furthermore, the input voltage is fed back to give the waveform of the reference current. The input current is sensed and compared with its reference value to generate the duty via current controller. The design specifications of controllers are as follows:

- 1. Controller Design of current loop
 - A. Bandwidth of current loop < 2k Hz
 - B. Phase margin > 45 degrees
- 2. Controller Design of voltage loop
 - A. Bandwidth of voltage loop < 120 Hz
 - B. Phase margin > 45 degrees

Table 3 Circuit parameters of PFC

| Parameters | Value |
|--|------------------------------|
| Input voltage (V _{in}) | • 110 V rms |
| Output voltage (V _o) | • 200 VDC |
| Input current (I _L) | • 3.63A rms |
| Inductor (L) | • 1321.7 <i>µ</i> H |
| Capacitor (C) | • 943 µF |
| Inductor DCR (R _{DCR}) | 125.3 mΩ |
| Capacitor ESR (R _{ESR}) | 76.37 mΩ |
| MOSFET on-resistance (Ron) | 0.175 Ω |
| Output power (P _o) | • 400 W |
| Switching frequency (f _{sw}) | • 20 KHz |

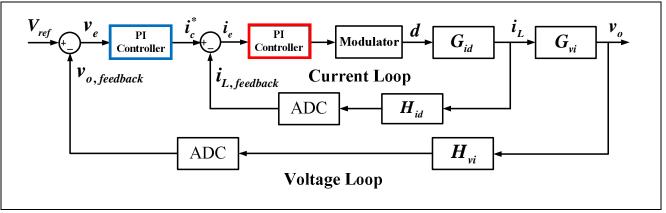


Figure 3 Block diagram of the developed PFC



2.1 Controller Design of Current Loop

The Bode plot for current loop is shown in Figure 4. As shown in Figure 4, the current loop band width BW= 1.18 kHz and PM = 70.4° . The designed results are:

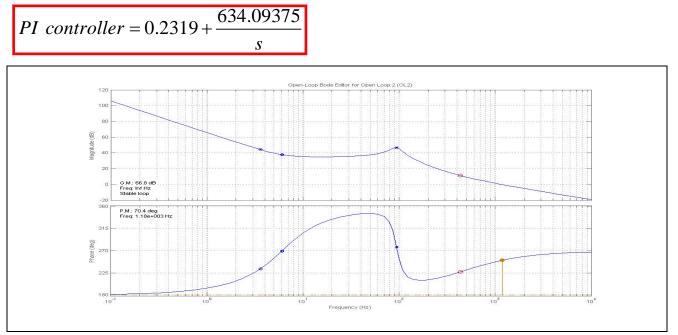
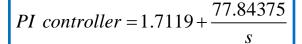


Figure 4 Bode lot of current loop

2.2 Controller Design of voltage loop

Figure 5 shows the Bode plot of voltage loop and the bandwidth of voltage loop is BW = 6.54Hz, $PM = 70.8^{\circ}$. The designed results are:



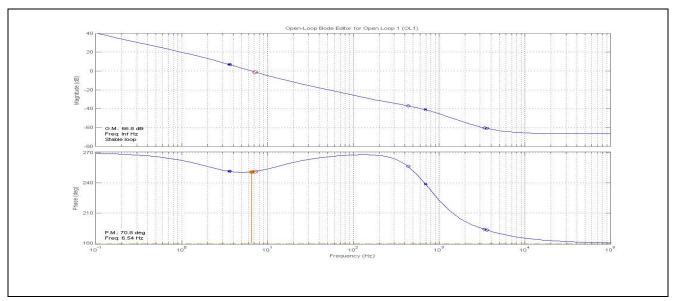


Figure 5 Bode lot of voltage loop



3. Controller Design of PMSM Drives

3.1 Modeling of PMSM

The mathematical model of PMSM referring to the synchronous reference frame can be derived as follows. Voltage equations:

$$\begin{bmatrix} v_{ds}^{e} \\ v_{qs}^{e} \end{bmatrix} = \begin{bmatrix} R_{s} + L_{d} p & -\omega_{e} L_{q} \\ \omega_{e} L_{d} & R_{s} + L_{q} p \end{bmatrix} \begin{bmatrix} i_{ds}^{e} \\ i_{qs}^{e} \end{bmatrix} + \begin{bmatrix} 0 \\ \omega_{e} i_{fd} L_{md} \end{bmatrix}$$
(1)

Torque equation:

$$T_{e} = \frac{3}{2} \cdot \frac{P}{2} \left[\lambda_{ds}^{e} i_{qs}^{e} - \lambda_{qs}^{e} i_{ds}^{e} \right]$$
⁽²⁾

Flux equations:

$$\lambda_{ds}^{e} = L_{d} i_{ds}^{e} + L_{md} i_{fd} \tag{3}$$

$$\lambda_{qs}^e = L_q i_{qs}^e \tag{4}$$

The state equation for the electrical circuit can be revised from (1) and shown in (5).

$$p\begin{bmatrix}i_{d_{s}}^{e}\\i_{q_{s}}^{e}\end{bmatrix} = \begin{bmatrix}-\frac{R_{s}}{L_{d}} & 0\\0 & -\frac{R_{s}}{L_{q}}\end{bmatrix}\begin{bmatrix}i_{d_{s}}^{e}\\i_{q_{s}}^{e}\end{bmatrix} + \begin{bmatrix}\frac{1}{L_{d}}(v_{d_{s}}^{e} + \omega_{e}L_{q}i_{q_{s}}^{e})\\\frac{1}{L_{d}}(v_{q_{s}}^{e} - \omega_{e}L_{d}i_{d_{s}}^{e} - \omega_{e}L_{md}i_{fd})\end{bmatrix}$$
(5)

As shown in (2), the torque can be controlled via q-axis current regulation if the controller keeps the d-axis current component equal to zero. By (2), (3), and (4), the torque equation becomes:

$$T_e = \frac{3}{2} \cdot \frac{P}{2} \left[\left(L_d - L_q \right) \dot{i}_{ds}^e \dot{i}_{qs}^e + \lambda_m \dot{i}_{qs}^e \right]$$
(6)

When the d-axis current component of magnetizing current equals to zero, the torque equation can be rewritten as:

$$T_{e} = \frac{3}{2} \cdot \frac{P}{2} (L_{md} i_{fd} i_{qs}^{e}) = \frac{3}{2} \cdot \frac{P}{2} (\lambda_{m} i_{qs}^{e})$$
(7)

Since the flux is constant (no demagnetization) for constant torque operation, the torque is controlled by the q-axis current. Furthermore, since the rotor flux, which aligns along the d-axis of synchronous frame, is perpendicular to the torque producing current, q-axis component of stator current, maximum torque can be obtained.

3.2 Vector Control of PMSM

The block diagram of vector-controlled PMSM drives for speed control/current control is shown in Figure 6. As shown in Figure 6, the PMSM drives consist of three controllers, including speed controller, q-axis and d-axis current controllers. To achieve decoupling control between q-axis and d-axis components, such that the linear control law can be used, the voltage decoupling mechanism is invoked in Figure 6. The decoupling terms shown in (8) and (9) are derived from (5). By (5), the block diagram for current controller design can be derived.

$$\begin{bmatrix} v_{ds}^{e} \\ v_{qs}^{e} \end{bmatrix} = L_{d} \begin{bmatrix} p + \frac{R_{s}}{L_{d}} & 0 \\ 0 & p + \frac{R_{s}}{L_{q}} \end{bmatrix} \begin{bmatrix} i_{ds}^{e} \\ i_{qs}^{e} \end{bmatrix} + \begin{bmatrix} -\omega_{e}L_{q}i_{qs}^{e} \\ \omega_{e}L_{d}i_{ds}^{e} + \omega_{e}L_{md}i_{fd} \end{bmatrix}$$

$$\begin{bmatrix} v_{dsdecouple} \\ v_{qsdecouple} \end{bmatrix} = \begin{bmatrix} -\omega_{e}L_{q}i_{qs}^{e} \\ \omega_{e}L_{d}i_{ds}^{e} + \omega_{e}L_{md}i_{fd} \end{bmatrix}$$

$$\tag{8}$$



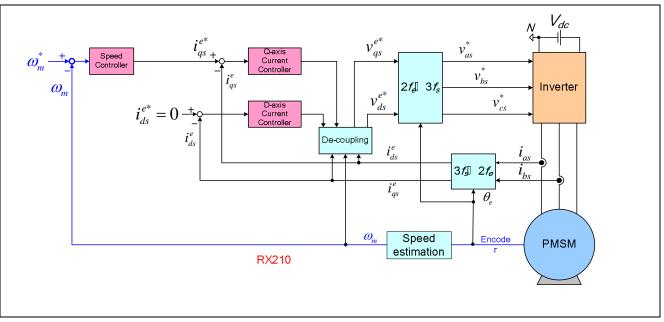


Figure 6 Block diagram of vector-controlled PMSM drives

3.3 Space Vector Modulation

A carried based PWM method which is shown to be equivalent as discussed in [1]. Based upon this method, the maximum linear modulation index can be extended from 1.0 p.u. to 1.1547 p.u.; base voltage = 0.5 Vdc. Moreover, V_{as}^* , V_{bs}^* , V_{cs}^* are used as reference to give T_a^* , T_b^* , and T_c^* which are ratios of phase voltage references to the half DC-link voltage, respectively. By these values, the related minimum and maximum are and used to give the pulse shift time as shown in (12). And the new pulse time is modified as shown in (13) to (15) to centralize the pulse in the half switching period as shown in Figure 7 in order to extend the linear modulation index.

$$T_{\max} = \max\left\{T_{a}^{*}, T_{b}^{*}, T_{c}^{*}\right\}$$
(10)

$$T_{\min} = \min\left\{T_{a}^{*}, T_{b}^{*}, T_{c}^{*}\right\}$$
(11)

$$T_{0} = \frac{1}{2} \left(T_{s} - T_{\max} - T_{\min} \right)$$
(12)

$$T_a = T_a^* + T_0 \tag{13}$$

$$T_b = T_b^* + T_0 \tag{14}$$

$$T_c = T_c^* + T_0 \tag{15}$$



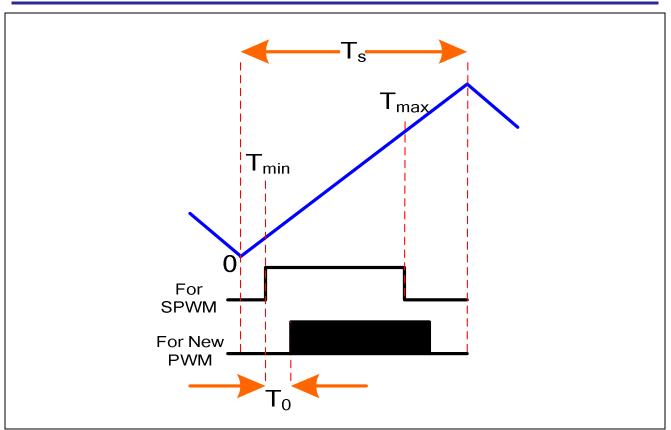


Figure 7 Diagram of T₀ component calculation

3.4 Design of d-axis Current Controller

Figure 8 shows the block diagram for d-axis current controller and its related plant. The designed bandwidth is 2 kHz. For the transfer function shown in (16), the closed-loop transfer function can be derived as shown in (17). Based upon pole-zero cancellation method, the relationship between the controller parameters and the plant parameter can be derived and shown in (18). The closed-loop transfer function with pole-zero cancellation can be further simplified as shown in (19). Therefore, the parameters of controller are derived as shown in (20) provided the bandwidth is given. The Bode plot for d-axis current controller is shown in Figure 9. As shown in Figure 9, the d-axis current controller band width BW = 2 kHz and magnitude = -3.04 dB.

$$G_{id}(s) = \frac{1}{R_s + L_{ds}s} = \frac{1}{2.65 + 6.4775 \times 10^{-3}s}$$
(16)

$$T_{d}(s) \Box \frac{i_{ds}^{e}}{i_{ds}^{e^{*}}} = \frac{(\frac{K_{p}s + K_{i}}{s})(\frac{1}{R_{s} + L_{ds}s})}{1 + (\frac{K_{p}s + K_{i}}{s})(\frac{1}{R_{s} + L_{ds}s})}$$
(17)

$$Let \quad \frac{K_p}{K_i} = \frac{L_{ds}}{R_s} \tag{18}$$

Td(s) can be rewritten as follow:

$$T_d(s) = \frac{K_i / R_s}{s + (K_i / R_s)}$$
(19)

$$K_i = 2.65 \times 12.566 \times 10^3 = 33299.9$$

$$K_i = (6.4775 \times 10^{-3} / 2.65) \times 33299.9 = 81.396265$$
⁽²⁰⁾



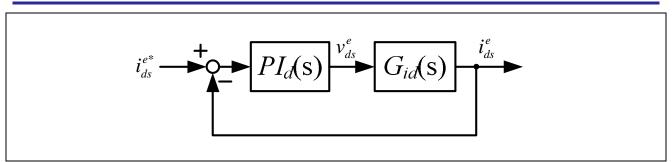


Figure 8 Block diagram for d-axis current controller design

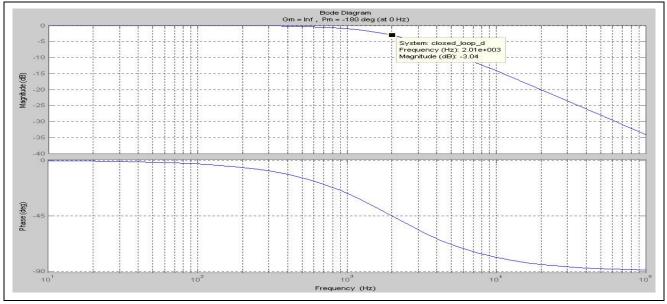


Figure 9 Bode plot of d-axis current controller

3.5 Design of q-axis Current Controller

Figure 10 shows the block diagram for q-axis current controller and its plant. The designed bandwidth is also 2 kHz. Similarly, the parameters of controller are derived as shown in (21) provided the bandwidth is given. The Bode plot for q-axis current controller is shown in Figure 11. As shown in Figure 11 the q-axis current controller band width BW = 2 kHz and magnitude = -3.02 dB.

$$K_i = 2.65 \times 12.566 \times 10^3 = 33299.9$$

$$K_i = (5.634 \times 10^{-3} / 2.65) \times 33299.9 = 70.796844$$

(21)

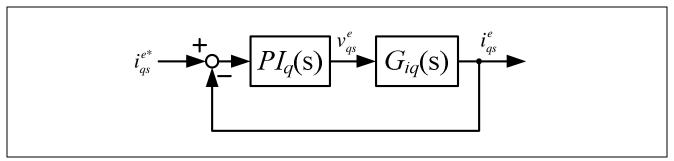


Figure 10 Block diagram for q-axis current controller design



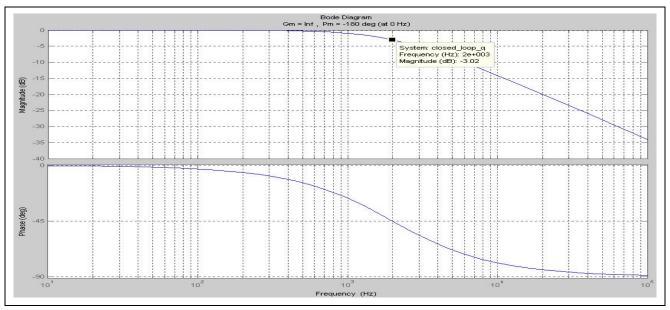


Figure 11 Bode plot of q-axis current controller

3.6 Design of Speed Controller

Figure 12 shows the block diagram for speed controller and its plant. The designed bandwidth is 200 Hz. For the transfer function shown in (22), the closed-loop transfer function can be derived as shown in (23). Based upon pole-zero cancellation method, the relationship between the controller parameters and the plant parameter can be derived and shown in (24). The closed-loop transfer function with pole-zero cancellation can be further simplified as shown in (25). Therefore, the parameters of controller are derived as shown in (26) provided the bandwidth is given. The Bode plot for speed controller is shown in Figure 13. As shown in Figure 13, the speed controller band width BW = 200Hz and magnitude = -3.06 dB.

$$G_t(s) = \frac{\omega_r}{B + J_s} = \frac{1}{0.0033 + 0.0008s}$$
(22)

Where

$$J = 0.0008 \ kg - m^{2}$$

$$B = 0.0033 \ Nt - m/(rad / sec)$$

$$T_{speed}(s) = \frac{(K_{p} + \frac{K_{i}}{s})(\frac{1}{J_{s} + B})}{1 + (K_{p} + \frac{K_{i}}{s})(\frac{1}{J_{s} + B})}$$
(23)
Let $\frac{K_{p}}{K_{i}} = \frac{J}{B}$
(24)

Tspeed(s) can be rewritten as follow:

$$T_{speed}(s) = \frac{K_p / J}{s + K_p / J}$$
(25)

$$\therefore J = 0.0008 \ kg - m^2 \ \therefore K_p = 0.36161$$

$$\therefore B = 0.0033 \ Nt - m^2 \ \therefore K_i = K_p \frac{B}{J} = 1.49165$$
(26)



(24)

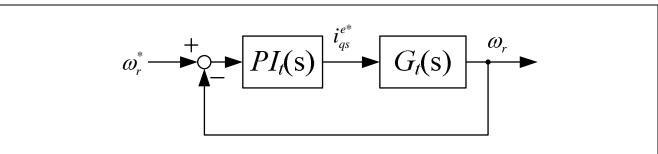


Figure 12 Block diagram for speed controller design

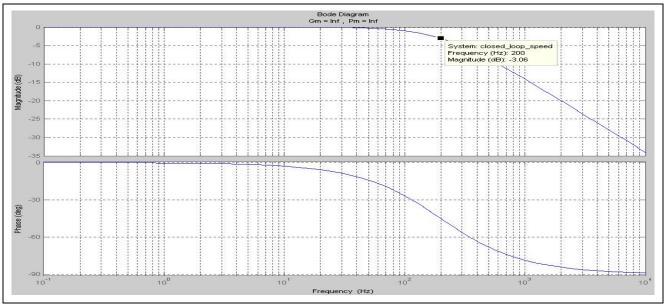


Figure 13 Bode plot of speed controller

4. Start Up Procedure

Figure 14 shows the two phase conduction mode and Figure 15 shows the three phase conduction mode, Figure 16 is the relationship of rotor attracts position from two phase conduction mode and three phase conduction mode, LS series location is two phase conduction mode, and LV series location is three phase conduction mode.

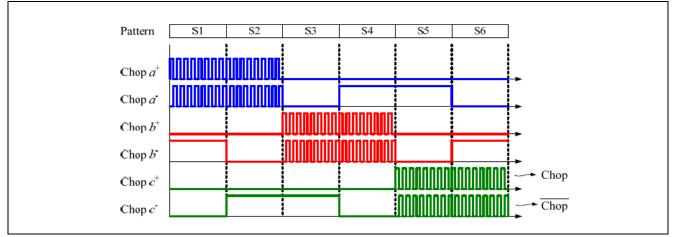


Figure 14 Two phase conduction mode



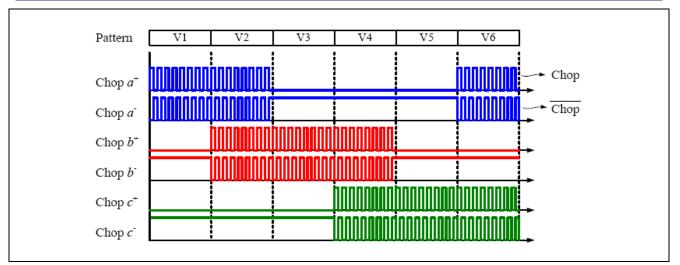


Figure 15 Three phase conduction mode

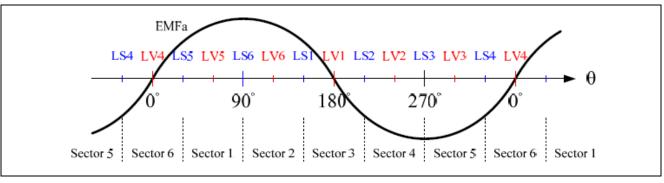


Figure 16 The relationship of rotor position



5. Software Implementation

Figure 17 shows the flow chart of PFC software implementation.

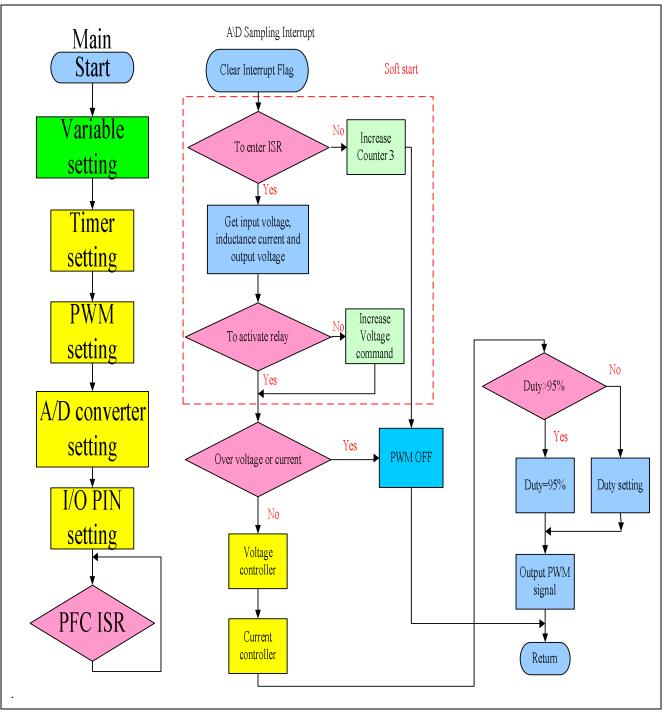


Figure 17 Flow chart of PFC software implementation



Figure 18 shows the flow chart of motor control software implementation.

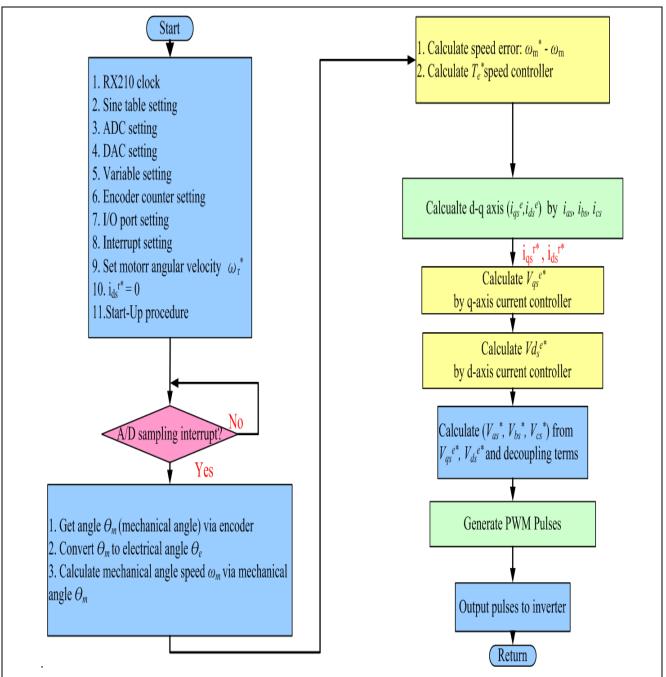


Figure 18 Flow chart of motor control software implementation

6. Experimental Results

Figure 19 shows the experimental set-up. The experimental system for integration test for PFC and vector controlled PMSM drives. The required calculations of block diagram shown in Figure 3 and Figure 6 are realized by RX210-based controlled board as shown in Fig. 20.



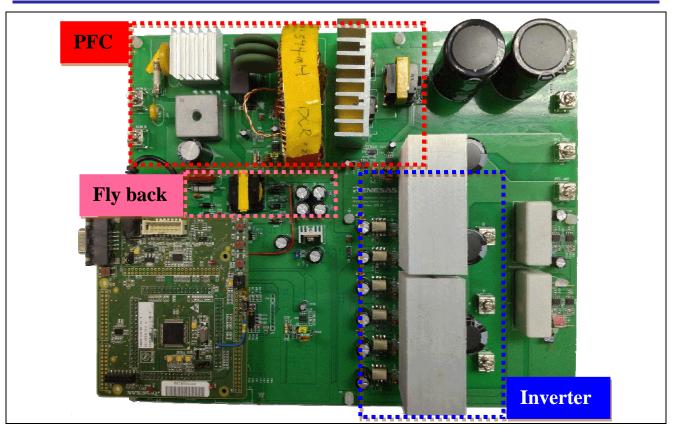


Figure 19 Experimental set up

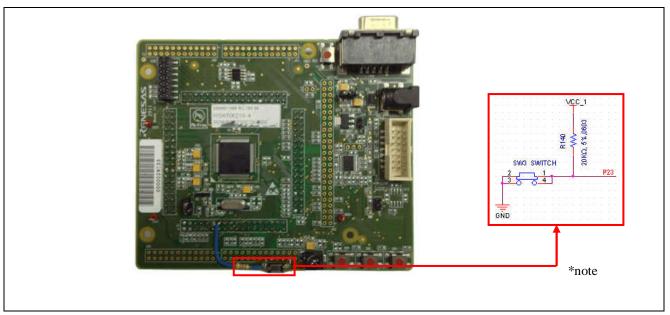


Figure 20 RX210-based control board

Note: A pin is connected with a pull-high resister and a switch button on the RSK, which is used to enable motor control procedure (i.e. P23 = low voltage, motor control start flag == 1)/



Figure 21 and Figure 22 shows the measured waveforms of power factor corrector without motor control. The experimental results show the power factor goes up to 0.98 under full load (400W) condition.

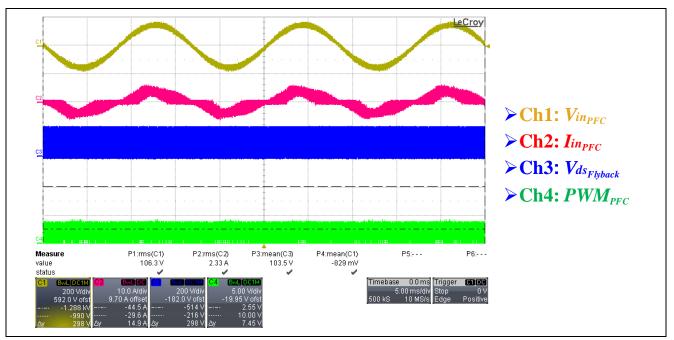


Figure 21 Load = 200W, Vout = 205.5V, PF = 0.963

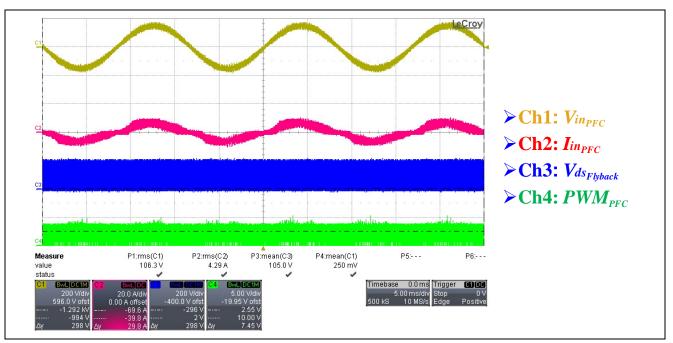


Figure 22 Load = 400W, Vout = 205.5V, PF = 0.982



Figure 23 and Figure 24 shows the measured waveforms of motor current and its speed without power factor corrector. The related motor speeds shown in Figure 23 and Figure 24 respectively.

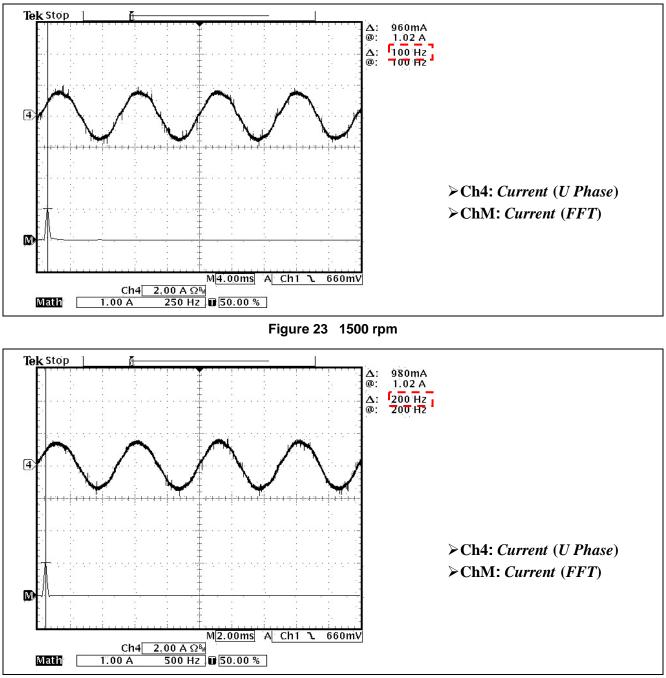


Figure 24 3000 rpm

Figure 25 shows the measured waveforms of motor control with power factor corrector. The related motor speeds shown in Figure 26 are 3000 rpm with power factor corrector.



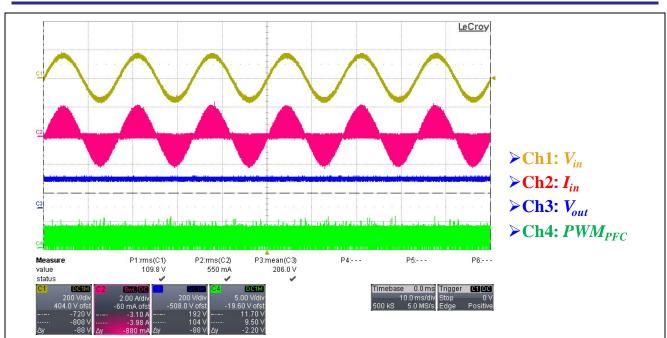


Figure 25 Measured waveforms of motor control with PFC

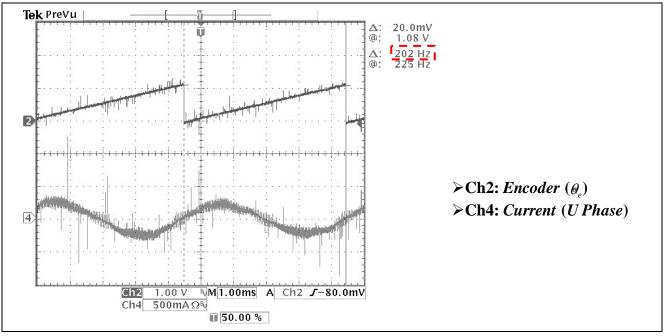


Figure 26 Relationship between encoder signal and U phase current

7. Conclusion

Power factor corrector and a vector-controlled PMSM drive are designed and implemented using RX210. Experimental results show the power factor goes up to 0.98 under full load condition and the motor speed goes up to its rated speed, 3000 rpm. These results demonstrate the results meeting the required specifications.



8. Reference

[1]. S. R. Bowes and Y. S. Lai, "The relationship between space vector modulation and Regular-sampled pulse-width modulation," IEEE Trans. on Industrial Electronics, Vol. 44, No. 5, pp. 670-679, 1997.



Website and Support

Renesas Electronics Website <u>http://www.renesas.com/</u>

Inquiries

http://www.renesas.com/contact/

All trademarks and registered trademarks are the property of their respective owners.



Revision Record

| | Date | Descript | | |
|------|--------------|----------|--|--|
| Rev. | | Page | Summary | |
| 1.00 | Nov 01, 2012 | _ | First edition issued | |
| 1.01 | Jan 23, 2013 | | Corrected only 3.3V power for VCC of RX210 on schematic file to fit the program using 3.3V | |
| | | | | |
| | | | | |
| | | | | |
| | | | | |
| | | | | |
| | | | | |
| | | | | |

General Precautions in the Handling of MPU/MCU Products

The following usage notes are applicable to all MPU/MCU products from Renesas. For detailed usage notes on the products covered by this document, refer to the relevant sections of the document as well as any technical updates that have been issued for the products.

1. Handling of Unused Pins

Handle unused pins in accord with the directions given under Handling of Unused Pins in the manual.

- The input pins of CMOS products are generally in the high-impedance state. In operation with an unused pin in the open-circuit state, extra electromagnetic noise is induced in the vicinity of LSI, an associated shoot-through current flows internally, and malfunctions occur due to the false recognition of the pin state as an input signal become possible. Unused pins should be handled as described under Handling of Unused Pins in the manual.
- 2. Processing at Power-on

The state of the product is undefined at the moment when power is supplied.

- The states of internal circuits in the LSI are indeterminate and the states of register settings and pins are undefined at the moment when power is supplied.
 In a finished product where the reset signal is applied to the external reset pin, the states of pins are not guaranteed from the moment when power is supplied until the reset process is completed.
 In a similar way, the states of pins in a product that is reset by an on-chip power-on reset function
 - are not guaranteed from the moment when power is supplied until the power reaches the level at which resetting has been specified.
- 3. Prohibition of Access to Reserved Addresses

Access to reserved addresses is prohibited.

- The reserved addresses are provided for the possible future expansion of functions. Do not access
 these addresses; the correct operation of LSI is not guaranteed if they are accessed.
- 4. Clock Signals

After applying a reset, only release the reset line after the operating clock signal has become stable. When switching the clock signal during program execution, wait until the target clock signal has stabilized.

- When the clock signal is generated with an external resonator (or from an external oscillator) during a reset, ensure that the reset line is only released after full stabilization of the clock signal.
 Moreover, when switching to a clock signal produced with an external resonator (or by an external oscillator) while program execution is in progress, wait until the target clock signal is stable.
- 5. Differences between Products

Before changing from one product to another, i.e. to a product with a different part number, confirm that the change will not lead to problems.

— The characteristics of an MPU or MCU in the same group but having a different part number may differ in terms of the internal memory capacity, layout pattern, and other factors, which can affect the ranges of electrical characteristics, such as characteristic values, operating margins, immunity to noise, and amount of radiated noise. When changing to a product with a different part number, implement a system-evaluation test for the given product.

Notice

- Descriptions of circuits, software and other related information in this document are provided only to illustrate the operation of semiconductor products and application examples. You are fully responsible for the incorporation of these circuits, software, and information in the design of your equipment. Renesas Electronics assumes no responsibility for any losses incurred by you or third parties arising from the use of these circuits, software, or information.
- Renesas Electronics has used reasonable care in preparing the information included in this document, but Renesas Electronics does not warrant that such information is error free. Renesas Electronics assumes no liability whatsoever for any damages incurred by you resulting from errors in or omissions from the information included herein.
- Renesas Electronics does not assume any liability for infringement of patents, copyrights, or other intellectual property rights of third parties by or arising from the use of Renesas Electronics products or technical information described in this document. No license, express, implied or otherwise, is granted hereby under any patents, copyrights or other intellectual property rights of Renesas Electronics or others.
- 4. You should not alter, modify, copy, or otherwise misappropriate any Renesas Electronics product, whether in whole or in part. Renesas Electronics assumes no responsibility for any losses incurred by you or third parties arising from such alteration, modification, copy or otherwise misappropriation of Renesas Electronics product.
- 5. Renesas Electronics products are classified according to the following two quality grades: "Standard" and "High Quality". The recommended applications for each Renesas Electronics product depends on the product's quality grade, as indicated below.
- "Standard": Computers; office equipment; communications equipment; test and measurement equipment; audio and visual equipment; home electronic appliances; machine tools; personal electronic equipment; and industrial robots etc.
- "High Quality": Transportation equipment (automobiles, trains, ships, etc.); traffic control systems; anti-disaster systems; anti-crime systems; and safety equipment etc.

Renesas Electronics products are neither intended nor authorized for use in products or systems that may pose a direct threat to human life or bodily injury (artificial life support devices or systems, surgical implantations etc.), or may cause serious property damages (nuclear reactor control systems, military equipment etc.). You must check the quality grade of each Renesas Electronics product before using it in a particular application. You may not use any Renesas Electronics product for any application for which it is not intended. Renesas Electronics shall not be in any way liable for any damages or losses incurred by you or third parties arising from the use of any Renesas Electronics product for which the product is not intended by Renesas Electronics.

- 6. You should use the Renesas Electronics products described in this document within the range specified by Renesas Electronics, especially with respect to the maximum rating, operating supply voltage range, movement power voltage range, heat radiation characteristics, installation and other product characteristics. Renesas Electronics shall have no liability for malfunctions or damages arising out of the use of Renesas Electronics products beyond such specified ranges.
- 7. Although Renesas Electronics endeavors to improve the quality and reliability of its products, semiconductor products have specific characteristics such as the occurrence of failure at a certain rate and malfunctions under certain use conditions. Further, Renesas Electronics products are not subject to radiation resistance design. Please be sure to implement safety measures to guard them against the possibility of physical injury, and injury or damage caused by fire in the event of the failure of a Renesas Electronics product, such as safety design for hardware and software including but not limited to redundancy, fire control and malfunction prevention, appropriate treatment for aging degradation or any other appropriate measures. Because the evaluation of microcomputer software alone is very difficult, please evaluate the safety of the final products or systems manufactured by you.
- 8. Please contact a Renesas Electronics sales office for details as to environmental matters such as the environmental compatibility of each Renesas Electronics product. Please use Renesas Electronics products in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive. Renesas Electronics assumes no liability for damages or losses occurring as a result of your noncompliance with applicable laws and regulations.
- 9. Renesas Electronics products and technology may not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any applicable domestic or foreign laws or regulations. You should not use Renesas Electronics products or technology described in this document for any purpose relating to military applications or use by the military, including but not limited to the development of weapons of mass destruction. When exporting the Renesas Electronics products or technology described in this document, you should comply with the applicable export control laws and regulations and follow the procedures required by such laws and regulations.
- 10. It is the responsibility of the buyer or distributor of Renesas Electronics products, who distributes, disposes of, or otherwise places the product with a third party, to notify such third party in advance of the contents and conditions set forth in this document, Renesas Electronics assumes no responsibility for any losses incurred by you or third parties as a result of unauthorized use of Renesas Electronics products.
- 11. This document may not be reproduced or duplicated in any form, in whole or in part, without prior written consent of Renesas Electronics.
- 12. Please contact a Renesas Electronics sales office if you have any questions regarding the information contained in this document or Renesas Electronics products, or if you have any other inquiries. (Note 1) Renesas Electronics' as used in this document means Renesas Electronics Corporation and also includes its majority-owned subsidiaries.
- (Note 2) "Renesas Electronics product(s)" means any product developed or manufactured by or for Renesas Electronics.

RENESAS

SALES OFFICES

Renesas Electronics Corporation

http://www.renesas.com

Refer to "http://www.renesas.com/" for the latest and detailed information.

Renease Electronics America Inc. 2880 Scott Bouleward Santa Clara, CA 95050-2554, U.S.A. Tei: +1-408-588-6000, Fax: +1-408-588-6130 Renease Electronics Canada Limited 1011 Nicholson Road, Newmarket, Ontario L3Y 9C3, Canada Tei: +1-905-598-5441, Fax: +1-905-898-3220 Renease Electronics Europe Limited Dukes Meadow, Millooard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K Tei: +44-162-8661-700, Fax: +449-211-6303-1327 Renease Electronics Europe Chimited Arcadiastrasse 10, 40472 Disseldorf, Germany Tei: +49-211-63030, Fax: +49-211-6303-1327 Renease Electronics (China) Co., Ltd. The Floor, Quantum Plaza, No.27 ZhiChunLu Haidian District, Beijing 100083, P.R.China Tei: +49-211-63030, Fax: +49-211-6303-1327 Renease Electronics (China) Co., Ltd. Unit 204, 205, AZIA Center, No. 1233 Lujiazui Ring Rd., Pudong District, Shanghai 200120, China Tei: +86-10-8235-1155, Fax: +86-10-8235-7679 Renease Electronics Kong Mang Co., Ltd. Unit 204, 205, AZIA Center, No. 1233 Lujiazui Ring Rd., Pudong District, Shanghai 200120, China Tei: +862-2469-318, Fax: +485-2486-7858 /-7898 Renease Electronics Fong Kong Limited Unit 1801-1613, 161F, Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong Tei: +852-24875-9900, Fax: +485 2-886-99209/044 Renease Electronics Taiwan Co., Ltd. 137, No, 353, FU Shing North Road, Taipei, Taiwan Tei: +885-24175-9900, Fax: +886 2-8175-9670 Renease Electronics Singapore Pte. Ltd. 20 Bendemeer Road, Unit #06-02 Hytlux Innovation Centre Singapore 339949 Tei: +65-213-12000, Fax: +856 2-8175-9570 Renease Electronics Magasia Sch.Bhd. Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No. 18, Jin Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tei: +608-7375, Fax: +608-7375, Fax: +780-737, Fax: +780-737,